

# Electro Optical Components, Inc.

5460 Skylane Boulevard, Santa Rosa, CA 95403 Toll Free: 855-EOC-6300

www.eoc-inc.com info@eoc-inc.com



# PbS near-infrared detector Line array bare chip



#### **Features**

- Thin-film encapsulation
- Very high sensitivity
- Suitable for automated wire-bonding

## **Applications**

- NIR spectroscopy
- Fire and spark detection
- Flame and moisture monitoring

### Electrical and optical characteristics per pixel

ĺ	Element	Peak wave-	20% cut-off	Peak D*		Time constant	Dark resistance
	temperature	length λ₽	wavelength	(620 Hz, 1 Hz)		[µs]	$R_D$ [M $\Omega$ ]
	[°C]	[µm]	λ <sub>C</sub> [μm]	[cm·Hz½/W]			
		Тур.	Тур.	Тур.	Min.	Тур.	
	22	2.7	2.9	1 · 10 <sup>11</sup>	$0.5 \cdot 10^{11}$	200	0.3 - 3

- Measured with 1550 nm LED, incident power 16 μW/cm<sup>2</sup>
- Measured in a voltage divider circuit with 50 V/mm
- Photo responsivity and detectivity are measured with constant load resistance ( $R_L = 1 \text{ M}\Omega$ ) and calculated for matched resistance

#### Possible mechanical characteristics

Number of pixels 1 - 512
Minimum pixel width 20 μm
Minimum pixel height 20 μm
Minimum pixel pitch 50 μm
Minimal chip length 3000 μm
Minimal chip height 3000 μm

Please contact us for an individual design: info@hertzstueck.de

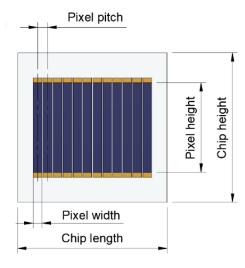


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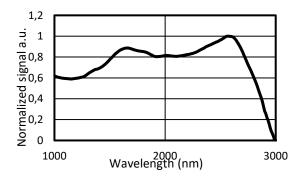


## **Exemplary mechanical characteristics**

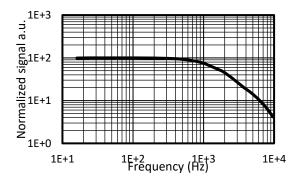
Type No.	Number of Pixels	Pixel pitch	Pixel width [µm]	Pixel height [μm]	Operating temperature
		[µm]			[°C]
PbS_Arr_256_0050_0040x0380	256	50	40 x 380		-30 to +70



## Typical spectral response per pixel



## Typical frequency response per pixel



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#### Die attach

- Use clean, soft rubber tip for pick and place handling
- UV-curing is not suitable due to permanent damage by UV light exposure
- Element temperature should never exceed +70°C

#### Wire-bonding

- Electrodes are optimized for room temperature Al-wire-bonding
- Element temperature should never exceed +70°C

#### **Options**

- Individual housing
- Bonding onto PCB
- Integrated optics

## **Handling**

- Active area is scratch sensitive, protect top surface from any mechanical contact
- Ensure dust-free environment for device handling
- Operating temperature: -30°C to +70°C

# Regulatory

For the use of Hertzstück™ PbS and PbSe infrared photodetectors in medical devices, monitoring and control instruments and consumer applications RoHS exemptions apply.

For automotive applications Hertzstück™ PbS and PbSe infrared photodetectors fall under ELV exemption.

#### **Storage**

- Storage temperature: -55°C to +70°C
- Exposure to UV light results in permanent damage
- Prevent exposure to UV and visible light